Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOS VII)

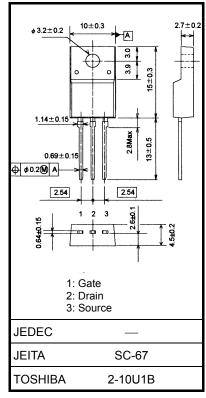
TK6A65D

Switching Regulator Applications

- Low drain-source ON resistance: $RDS(ON) = 0.95 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 4.0 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 650 \ V)$
- Enhancement-mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Characteristics			Symbol	Rating	Unit	
Drain-source voltage			V _{DSS}	650	V	
Gate-source voltage			V _{GSS}	±30	V	
Drain current	DC (Note	1)	ID	6	А	
	Pulse (Note	1)	I _{DP}	24	A	
Drain power dissipation (Tc = 25° C)			PD	45	W	
Single pulse avalanche energy (Note 2)			E _{AS}	281	mJ	
Avalanche current			I _{AR}	6	А	
Repetitive avalanche energy (Note 3)			E _{AR}	4.5	mJ	
Channel temperature			T _{ch}	150	°C	
Storage temperature range			T _{stg}	-55 to 150	°C	

Absolute Maximum Ratings (Ta = 25°C)



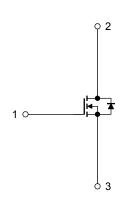
Weight : 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Internal Connection



Start of commercial production 2012-01

Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 13.8 mH, R_G = 25 Ω , I_{AR} = 6 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

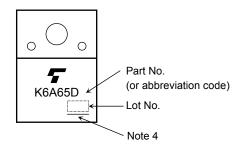
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_	—	±1	μA
Drain cut-off current		I _{DSS}	$V_{DS} = 650 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source bre	Drain-source breakdown voltage		$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	650			V
Gate threshold voltage		V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	rain-source ON resistance R _{DS (ON)} V		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$		0.95	1.11	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$	1.0	4.0		S
Input capacitance		C _{iss}			1050		pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$		5		
Output capacitance		C _{oss}		_	100		
Switching time	Rise time	tr	$10 V$ V_{GS} $0 V$		25		- ns
	Turn-on time	t _{on}			60		
	Fall time	t _f			10	_	
	Turn-off time	t _{off}	$V_{DD} \approx 200 \text{ V}$ Duty \leq 1%, $t_W = 10 \ \mu s$		75	_	
Total gate charge Qg		Qg			20		
Gate-source charge		Q _{gs}	V _{DD} ≈ 400 V, V _{GS} = 10 V, I _D = 6 A		13		nC
Gate-drain charge		Q _{gd}]	_	7	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	6	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_		24	А
Forward voltage (diode)	V _{DSF}	$I_{DR} = 6 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 6 \text{ A}, V_{GS} = 0 \text{ V},$	_	1300	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	10	_	μC

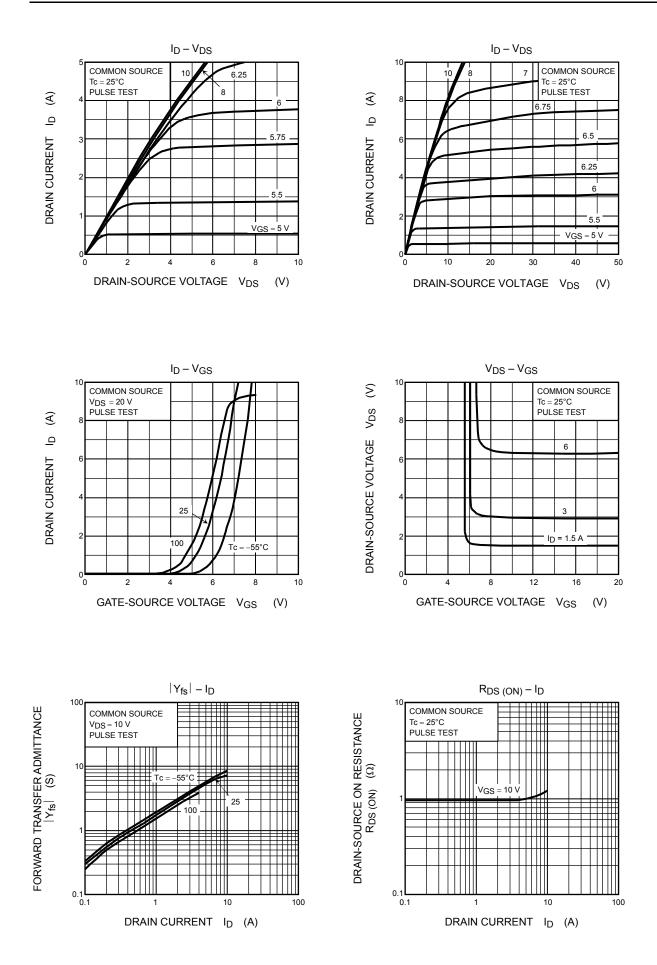
Marking



Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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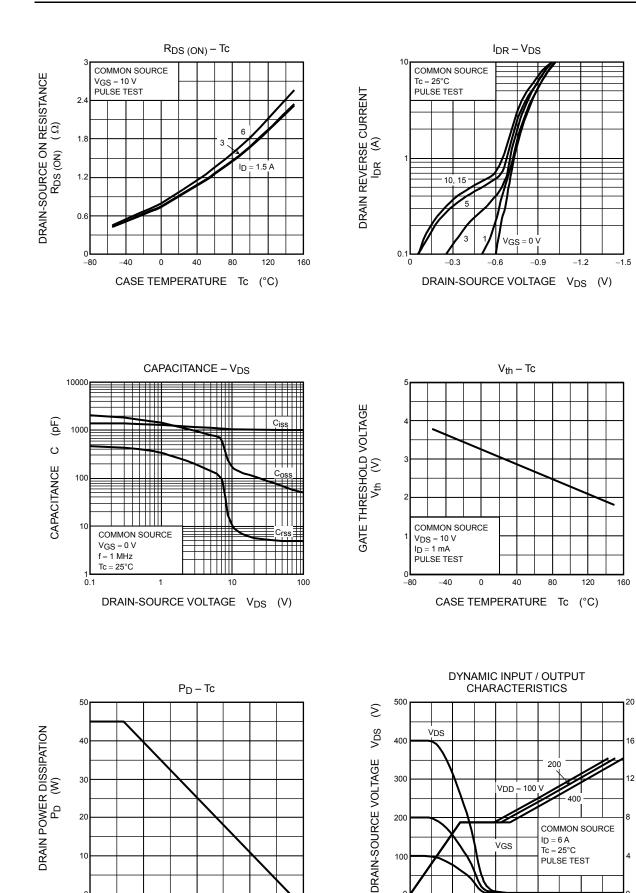
40

80

CASE TEMPERATURE Tc (°C)

120

160



n

30

S

V_{GS}

GATE-SOURCE VOLTAGE

PULSE TEST

24

(nC)

18

4

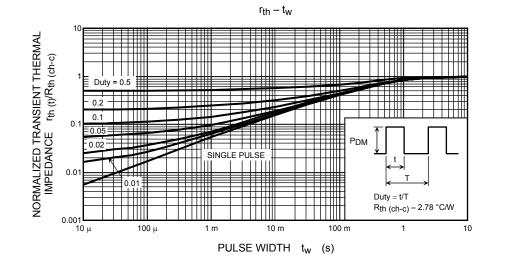
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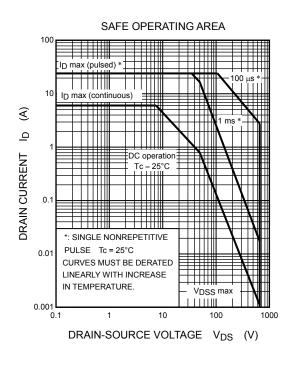
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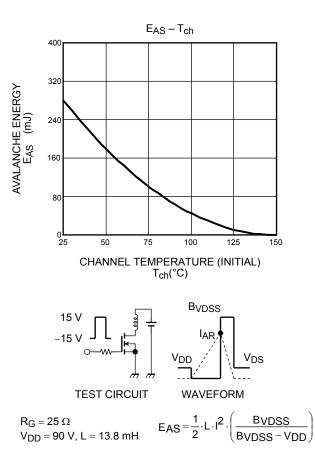
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12

TOTAL GATE CHARGE Qg







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